

COMPLETE THIS FORM TO INITIATE SUPPLIER SCOUTING MEPNN Supplier Scouting Opportunity Synopsis

*The submitting entity agrees to notify NIST MEP of the status of actions taken as a result of this scouting instance within 30 days after receiving a results report. For instances where the submitting entity is an MEP Center submitting on behalf of a client, the MEP Center agrees to notify NIST MEP on behalf of their client. For instances where the submission is direct from federal/state agencies or is a private company, the submitting federal/state agency or private company entity agrees to notify NIST MEP. Notification should be via email to scouting@nist.gov, indicating the following:

- Contact with matches identified in report complete and supply contract awarded, process complete
- Contact with matches identified in report complete and no supply contract awarded, process complete
- Contact with matches identified in report complete and supply negotiations underway, process in progress
- Contact with matches identified in report underway; supply negotiations not yet begun; process in progress
- Contact with matches identified in report not yet begun, process in progress
- Contact with matches identified in report will not occur within the next 6-months, process complete

ICP RIE for Etching Silicon with Hydrogen Bromide and Chlorine

Item to be Scouted

Please describe the item application/ the end use of item.* Provide the item number if applicable: (N95 Mask vs Protective Mask).

The National Institute of Standards and Technology (NIST) seeks information on commercial vendors that can provide an inductively coupled plasma (ICP) reactive ion etcher for etching silicon with hydrogen bromide (HBr) and chlorine (CI2) to support nanofabrication in the Center for Nanoscale Science and Technology (CNST) user facility. The system will be sited and used as a shared resource accessible to researchers from industry, academia, NIST, and other government agencies in the CNST NanoFab. This ICP silicon etching system is a pattern transfer tool that uses HBr or CI2 and other chemicals to fabricate micron- and nano-scale structures in silicon substrate. Applications include fabricating nano-semiconductor and nano-photonic devices.

2022		
		Number (NIST MEP use)
3332		- Annalysis NALCE Could Hillingurg
	-	r/product <u>NAICS Code</u> , if known
TECHNI	1. Supplier	a. Type of supplier being sought* Manufacturer Contract Manufacturer Distributor Other
		b. Reason for scouting submission*
TECHNICAL INFORMATION:	Information	 2nd Supplier Price Re-shore Past supplier no longer available New Product Startup Other
ION:		
	2. an	a. Describe the manufacturing processes (elaborate to provide as much detail as possible).*
	2. Summary of Te and Performance	Item to be purchased as a standalone unit
	ry c ma	b. Provide dimensions / size / tolerances / performance specifications for the item.*
	chnical Specifications Requirements:	this ICP system is a pattern transfer tool that uses an inductively coupled plasma to fabricate micron- and nano-scale structures in silicon, primarily using HBr, Cl2 and other etching gases. This new ICP silicon etcher will be used to minimize the system down time, mprove the process repeatability and add new NanoFab's etching process capabilities. 2. Tool configuration: The system must be equipped with following components: 1) A load-lock that transfers the samples in and out of the process chamber. 2) A process chamber hat is compatible with reactive chemicals such as HBr, Cl2, Argon (Ar), Oxygen (O2) and other etching gases. 3) An ICP source that operates from 0 to 2000 W. 4) A RIE electrode that operates from 0 to 500 W or higher. 5) A pumping system that is compatible with HBr, Cl2 and other chemistries. 6) Software that supports both manual and automatic operations. 7) Safety interlocks to keep users safe. 3. Wafer compatibility and handling: 1) The system shall be able to process substrates with various sizes including 75 mm, 100 mm, 150 mm and 200 mm substrate. 2) The system shall have a wafer carrier loading system which can adapt various wafer sizes without opening the process chamber. 3) The wafer carrier loading system shall have wafer top clamping and backside helium cooling. 2. Established process ibrary: 1) The system shall include process parameters such as etch rate, selectivity, and profile with scanning electron microscope pictures.



			c. List required materials needed to make the product, including materials of product components.*					
		Item to be purchased as a standalone unit						
		N	d. Are there applicable certification requirements?*					
		2. Su	Please explain					
		mma						
		ary o						
		fTec	e. Are there applicable regulations?* 🗌 Yes 🔹 No					
		hnic	Please explain					
		al Sp						
		ecifi						
	cont:	Summary of Technical Specifications	f. Are there any other standards, requirements, etc.?* Ves No					
	Ħ	ins a	Please explain					
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		erfor						
		man	g. Additional Comments: Is there other information that would impact the item's performance or usefulness? Please explain.					
		and Performance Requirements						
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		nts						
B	Pr	<u>.</u> 3	3a. Estimated potential business volume (i.e., # Units Per Day, Month, Year) *:					
BUSIN	Pricing	Volu	One unit					
	1	ime and						
INFC		Ind	b. Estimated target price / unit cost information (flexible and negotiable not accepted) *:					
ESS INFORMATION:		ľ	\$700,000.00					
ATIO		4	a. When is it needed by? (Immediate, 30 Days, 6 months, etc.)*					
N :			ASAP					
		very	b. Describe packaging requirements (i.e., individually/group packaging)*					
		Requ	Flexible					
		reme	c. Where will this item be shipped?*					
		ents:	NIST, 100 Bureau Drive, Gaithersburg, MD 20899					
			The F, Tee Baroad Brite, Califordiag, MB 20000					
	Ad dit	'n	Is there other information you would like to include?					

MEP National Network [™]										
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Photos or diagrams of the item (helpful but not required).